NSN 5961-01-035-2192

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-035-2192 **Inclosure Material:** Ceramic **Overall Length:** 0.300 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.145 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 340.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 4.00 milliamperes all primaries horsepower metric and 13.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 8.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Terminals or terminal surfaces, options silver **Precious Material:** Silver **Test Data Document:** 26916-019-005381 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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